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Conductance from Non-perturbative Methods I

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A bstract: We investigate dierent methods to compute the DC conductance in a quantum wire doped with some impuritied by exploiting the integrability of the theories under consideration. As an essential ingredient in all methods we evaluate the rejection and transmission amplitudes of the impurities for a variety of defects. When the impurities in the wire are coupled to an external three dimensional laser eld, we predict the generation of harm onic emission spectra. We propose a modied version of the well-known K ubo formula, which incorporates the impurities of the system and evaluate the current-current two-point correlation function it involves with the help of a form factor expansion. A comparison with the corresponding quantities computed in a Landauer transport theory picture is carried out in part II.

The work I want to report about is based on a series of papers [1, 2, 3, 4, 5, 6] with an emphasis on the rst two. O lalla Castro-A lyaredo will present the second part of this talk.

1. G eneralities on conductance

In the context of 1+1 dimensional quantum—eld theories an impressive arsenal of non-perturbative techniques has been developed over the last 25 years. The original motivation was to use the lower dimensional set up as a testing ground for general conceptual ideas and possibly to apply them in the context of string theory, such that most of the work in this area can be characterized very often as rather formal. However, lately the experimental techniques have advance to such an extent that one might realistically hope to measure various quantities which can be predicted based on these approaches.

One of those quantities, which is particularly easy to access, is the conductance (conductivity). It can be measured in general directly without perturbing very much the behaviour of the system, e.g. a rigid-lattice bulk metal, such that the uncertainty of experimental artefacts is reduced to a minimum. Indeed, there have been some fairly recent

m easurements [7] of this quantity in 1+1 dimensions and the challenge is of course to explain these data theoretically and possibly inspire more experiments of a similar type.

There exist two main theoretical descriptions to compute the conductance, the Kubo formula [8,9], which is the outcome of a dynamical linear-response theory and the Landauer-Buttinger theory [10], which is a semi-classical transport theory. The main purpose of the work I want to present is a comparison between these two descriptions by employing non-perturbative methods of 1+1 dimensional integrable models. It is in this sense the wording non-perturbative is to be understood, that is despite the fact that the overall theoretical description is of a perturbative nature, within these frameworks we use non-perturbative methods. I will concentrate on our proposal of a generalized Kubo formula and in the second part, presented by O lalla Castro-A lvaredo, the computations within the Landauer-Buttinger transport theory framework will be presented.

I will start by anticipating the quantities we have to compute. The system we consider is a one dimensional quantum wire doped with some in purities (defects). For the time being we leave the theory describing the wire and also the nature of the impurities unspecied. In linear response theory one essentially needs the Fourier transform of the current two-point correlation function. This so-called K ubo formula has been adopted to a situation with a boundary [11]. Since this only captures elects coming from the constriction of the wire a generalization to a set up with defects was needed, which we proposed in [1] as

G (T) =
$$\lim_{! \to 0} \frac{1}{2!} \sum_{j=1}^{Z_{j}} dt e^{i!t} hJ(t)Z J(0)i_{T,m}$$
: (1.1)

Here the defect operator Z enters in-between the two local currents J within the temperature T and mass m dependent correlation function. The M atsubara frequency is denoted by !.

The other possibility of determ ining the conductance which we want to study, is a generalization of the Landauer-Buttinger transport theory picture. Within this fram ework a proposal for the conductance through a quantum wire with a defect (impurity) has been made in [12, 13]

$$G (T) = \begin{cases} X & \lim_{\substack{i \in (\frac{1}{i} - \frac{r}{i})! \ 0}} \frac{q_{\underline{i}}}{2} & d & \lim_{\substack{i \in (\mathbf{j}, T; \frac{1}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1} & () / f & \lim_{\substack{i \in (\mathbf{j}, T; \frac{r}{i}) / T_{\underline{i}} \ 0}} \frac{r}{1}$$

which we only modify to accomm odate parity breaking. This means we allow the transmission amplitudes for a particle of type i with charge q_i passing with rapidity—through a defect of type—from the left T_i —() and right T_i —() to be dierent. The density distribution function—i—(;T; i) depends on the temperature T, and the potential at the left—i and right—i—constriction of the wire.

The main quantities we have to compute before we can evaluate (1.1) and (1.2) are the transmission amplitudes T_i , the current-current correlation functions $h::i_{T,m}$ and the density distributions i. We obtain all of them non-perturbatively, the T's by means of potential scattering theory, e.g. [14], the correlation function from a form factor [15, 16, 17] expansion and the 's from a thermodynamic Bethe (TBA) ansatz [18] analysis.

2. Im purity system s

2.1 Constraints from the generalized Yang-Baxter equations

Let me start with the evaluation of the transm ission amplitudes, since they will be required in (1.1) as well as in (1.2). One of the great advantages of integrability in 1+1 dimensional models is that the n-particle scattering matrix factorises into two-particle S-matrices, which can be determined by some constraining equations such as the Yang-Baxter [19] and bootstrap equations [20]. Similar equations hold in the presence of a boundary [21, 22, 23] or a defect [24, 4]. It is clear that with regard to the conductance a situation with a pure boundary, i.e. non-trivial elects on the constrictions, or purely transmitting defects will be rather uninteresting and we would like to consider the case when R and T are simultaneously non-vanishing. Unfortunately, it will turn out that for that situation the Yang-Baxter equations are so constraining that not many integrable theories will be left to consider. Thus this section serves essentially to motivate the study of the free Fermion, which after all is very close to a realistic system of electrons propagating in quantum wires.

We label now particle types by Latin and degrees of freedom of the impurity by G reek letters, the bulk scattering matrix by S, and the left/right rejection and transmission amplitudes of the defect by R = R and T = T, respectively. Then the transmission and rejection amplitudes are constrained by the \unitarity" relations

$$R_{i}^{j}()R_{j}^{k}() + T_{i}^{j}()T_{j}^{k}() = k_{i}^{j};$$
 (2.1)

$$R_{i}^{j}()T_{i}^{k}()+T_{i}^{j}()R_{i}^{k}()=0;$$
 (2.2)

and the crossing-herm iticity relations

$$R_{||}() = R_{||}() = S_{j|}(2)R_{j}(i);$$
 (2.3)

$$T_{||}() = T_{||}() = T_{||}(i) :$$
 (2.4)

The equations (2.1) and (2.2) also hold after perform ing a parity transform ation, that is for $R \$ R and $T \$ T.

Depending now on the choice of the initial asymptotic condition one can derive the following two non-equivalent sets of generalized Yang-Baxter equations by exploiting the associativity of the extended Zam olodchikov-Faddeev algebra [21, 22, 23, 24, 4]

$$S(_{12})[I R(_{1})]S(_{12})[I R(_{2})] = [I R(_{2})]S(_{12})[I R(_{1})]S(_{12});$$
 (2.5)

$$S(_{12})[I R(_{1})]S(_{12})[I T(_{2})] = R(_{1}) T(_{2});$$
 (2.6)

$$S(_{12})[T(_{2}) T(_{1})] = [T(_{1}) T(_{2})]S(_{12});$$
 (2.7)

and

$$R(_1) R(_2) = R(_1) R(_2);$$
 (2.8)

$$[T (2) I]S(12)[R (1) I]S(12) = T (2) R (1);$$
 (2.9)

$$[I \quad T \quad (2)] S \quad (12) [I \quad R \quad (1)] S \quad (12) = R \quad (1) \quad T \quad (2); \tag{2.10}$$

$$[T (_1) \quad I]S (\hat{_{12}})[T (_2) \quad I] = [I \quad T (_2)]S (\hat{_{12}})[I \quad T (_1)]:$$

We used here the convention (A B $_{ij}^{kl}$ = A $_{i}^{k}$ B $_{j}^{l}$ for the tensor product and abbreviated the rapidity sum $_{12}^{}$ = $_{1}$ + $_{2}$ and dierence $_{12}$ = $_{1}$ + $_{2}$ 0 nce again the same equations also hold for R \$ R and T \$ T.

A part from some discrepancies in the indices the equations (2.5)-(2.7) correspond to a more simplied, in the sense that there were no degrees of freedom in the defect and parity invariance is assumed, set of equations considered previously in [24]. For diagonal scattering it was argued in [24] that one can only have rejection and transmission simultaneously when S = 1. In [4] a more general set up which includes all degrees of freedom was studied. A second set of equations (2.8)-(2.11), which is not equivalent to (2.5)-(2.7) was found. It was shown that in the absence of degrees of freedom in the defect no theory which has a non-diagonal bulk scattering matrix admits simultaneous rejection and transmission. This result even holds for the completely general case including degrees of freedom in the defect upon a mild assumption on the commutativity of R and T in these variables. It was further shown that besides S = 1 also the Federbush model [25] and the generalized coupled Federbush models [6] allow for R $\stackrel{\leftarrow}{\bullet}$ 0 and T $\stackrel{\leftarrow}{\bullet}$ 0.

2.2 M ultiple impurity systems

Them ost interest situation in impurity systems arises when instead of a single one considers multiple defects, since that leads to the occurrence of resonance phenomena and when the number of defects tends to in nity even to band structures. Assuming that the distance between the defects is small in comparison to the length of the wire one can easily construct the transmission and rejection amplitudes of them ultiple defect system from the knowledge of the corresponding quantities in the single defect system. For instance for two defects one obtains

$$T_{i} () = \frac{T_{i} ()T_{i} ()}{1 R_{i} ()R_{i} ()}; \qquad R_{i} () = R_{i} () + \frac{R_{i} ()T_{i} ()T_{i} ()}{1 R_{i} ()R_{i} ()}; \qquad (2.12)$$

$$T_{i}() = \frac{T_{i}()T_{i}()}{1 R_{i}()R_{i}()}; \qquad R_{i}() = R_{i}() + \frac{R_{i}()T_{i}()T_{i}()}{1 R_{i}()R_{i}()}; \qquad (2.13)$$

These expressions allow for a direct intuitive understanding, for instance we note that the term $[1 \quad R_i\ (\)R_i\ (\)]^1= \prod_{n=1}^p [R_i\ (\)R_i\ (\)]^n$ simply results from the in nite number of reactions which we have in-between the two defects. This is of course well known from Fabry-Perot type devices of classical and quantum optics. For the case T=T; R=R the expressions (2.12) and (2.13) coincide with the formulae proposed in [26]. When absorbing the space dependent phase factor into the defect matrices, the explicit example presented in [24] for the free Fermion perturbed with the energy operator agree almost for T=T; R=R with the general formulae (2.12). They disagree in the sense that the equality of R_i () and R_i () does not hold for generic; as stated in [24].

It is now straightforward to generalize the expressions for an arbitrary number of defects, say n, in a recursive m anner

$$T_{i}^{\sim}() = \frac{T_{i}^{1} = k () T_{i}^{k+1} = n ()}{1 R_{i}^{1} = k () R_{i}^{k+1} = n ()}; \qquad 1 < k < n; \qquad (2.14)$$

$$R_{i}^{\sim}() = R_{i}^{1 ::: k}() + \frac{R_{i}^{k+1 ::: n}()T_{i}^{1 ::: k}()T_{i}^{1 ::: k}()}{1 R_{i}^{1 ::: k}()R_{i}^{k+1 ::: n}()}; \quad 1 < k < n : \quad (2.15)$$

We encoded here the defect degrees of freedom into the vector $\sim f_1$; and g; Sim ilar expressions also hold for T_i^{\sim} () = T_i^{-1} in () and R_i^{\sim} () = R_i^{-1} in ().

A lternatively, we can de ne, in analogy to standard quantum mechanicalmethods (see e.g. [14]), a transmission matrix which takes the particle i from one side of the defect of type to the other

$$M^{i}() = \begin{cases} T_{i}()^{1} & R_{i}()T_{i}()^{1} \\ R_{i}()T_{i}()^{1} & T_{i}()^{1} \end{cases} : (2.16)$$

Then alternatively to the recursive way (2.14) and (2.15), we can also compute the multidefect transm ission and rejection amplitudes as

$$T_{i}^{\circ}() = M_{k}^{i}() = R_{i}^{\circ}() = M_{k}^{i}() =$$

This formulation has the virtue that it is more suitable for numerical computations, since it just involves matrix multiplications rather than recurrence operations. In addition it allows for an elegant analytical computation of the band structures for n! 1, which I will however not comment upon further in this talk.

2.3 Constraints from potential scattering theory

As we argued in section 2.1., in order to obtain a non-trivial conductance we are lead to consider free theories, possibly with some exotic statistics. Trying to be as close as possible to some realistic situation, i.e. electrons, we consider rist the free Fermion, which with a line of defect was rist treated in [27]. Thereafter it has also been considered in [28, 24] and [29] from dierent points of view. In [27, 28, 24] the defect line was taken to be of the form of the energy operator and in [29] also a perturbation in form of a single Fermion has been considered. In [1] we treated a much wider class of possible defects.

Let us consider the Lagrangian density for a complex free Ferm ion with 'defects¹

$$L = (i @ m) + D^{n} (;; @_{t}; @_{t}) (x x_{n}) :$$
 (2.18)

The defect is described here by the functions D n (; e_t ; e_t); which we assume to be linear in the Ferm i elds , and their time derivatives. We can now proceed in

$$x = (x^{0}; x^{1});$$
 $p = (m cosh j m sinh);$ $g^{0} = g^{11} = m^{01} = m^{10} = 1;$ $0 = 0 1 j m sinh);$ $0 = 0 1 j m sinh);$

We adopt relativistic units $1 = c = \sim = m$ $e^2 137$ as mostly used in the particle physics context rather than atom ic units $1 = e = \sim = m$ c=137 m ore natural in atom ic physics.

¹W e use the conventions:

analogy to standard quantum mechanical potential scattering theory (see also [28, 24, 29]) and construct the amplitudes by adequate matching conditions on the eld. We consider rst a single defect at the origin which su ces, since multiple defect amplitudes can be constructed from the single defect ones, according to the arguments of the previous section. We decompose the elds of the bulk theory as (x) = (x) + (x) + (x) + (x), with (x) being the Heavyside unit step function, and substitute this ansatz into the equations of motion. As a matching condition we read of the factors of the delta function and hence obtain the constraints

$$i^{1}(_{+}(x)) \qquad (x))\dot{j}_{k=0} = \frac{\text{@D}}{\text{@}(x)}_{x=0} \qquad \frac{\text{@}}{\text{@t}} \frac{\text{@D}}{\text{@}(\text{@t}(x))}_{x=0} : \qquad (2.19)$$

We then use for the left () and right (+) parts of the well-known Fourier decomposition of the free eld

$$\frac{f}{j}(x) = \frac{d}{p - \frac{1}{4}} a_{j}()u_{j}()e^{-ip_{j}} + a_{j}^{y}()v_{j}()e^{ip_{j}} ; \qquad (2.20)$$

with the Weylspinors

$$u_{j}() = i^{5}v_{j}() = \frac{r}{\frac{m_{j}}{2}} e^{\frac{!}{2}}$$
 (2.21)

and substitute them into the constraint (2.19). Treating the equations obtained in this manner componentwise, stripping of the integrals, one can bring them thereafter into the form

$$a_{j}$$
; () = R_{j} () a_{j} ; () + T_{j} () a_{j} ; () ; (2.22)

which de nest he rejection and transmission amplitudes in an obvious manner. When parity invariance is broken, the corresponding amplitudes from the right to the left do not have to be identical and we also have

$$a_{j;+}$$
 () = T_{j} () $a_{j;+}$ () + R_{j} () $a_{j;+}$ (): (2.23)

The creation and annihilation operators $a_i^y(\cdot)$ and $a_i(\cdot)$ satisfy the usual ferm ionic anti-commutation relations $fa_i(\cdot_1); a_j(\cdot_2)g = 0$, $fa_i(\cdot_1); a_j^y(\cdot_2)g = 2$ $i_j(\cdot_{12})$. In this way one may construct the R's and T's for any concrete defect which is of the generic form as described in (2.18). After the construction one may convince oneself that the expressions found this way indeed satisfy the consistency equations like unitarity (2.1), (2.2) and crossing (2.3), (2.4). Unfortunately the equations (2.1)–(2.4) can not be employed for the construction, since they are not restrictive enough by them selves to determ ine the R's and T's. We consider now some concrete examples:

2.3.1 Im purities of Luttinger liquid type D (;) = $(g_1 + g_2)^0$) Luttinger liquids [30] are of great interest in condensed matter physics, which is one of the motivations for our concrete choice of the defect D (;) = $(g_1 + g_2)^0$). When taking the conform all imit of the defect one obtains an impurity which played a role in this

context, see e.g. [31], after elim inating the bosonic number counting operator. In the way outlined above, we compute the related transm ission and rejection amplitudes

$$R_{j}(;g_{1};g_{2}; y) = R_{j}(;g_{1};g_{2};y) = \frac{4i(g_{2} + g_{1} \cos h)e^{2iym \sinh}}{(4 + g_{1}^{2} g_{2}^{2}) \sinh 4i(g_{1} + g_{2} \cosh)}; (2.24)$$

$$R_{|(;g_{1};g_{2}; y) = R_{|(;g_{1};g_{2};y)} = \frac{4i(g_{1} g_{2} \cos h)e^{2iym \sinh}}{(4 + g_{1}^{2} g_{2}^{2}) \sinh 4i(g_{1} g_{2} \cosh)}; (2.25)$$

$$T_{j}(;g_{1};g_{2}) = T_{j}(;g_{1};g_{2}) = \frac{(4 + g_{2}^{2} g_{2}^{2}) \sinh}{(4 + g_{1}^{2} g_{2}^{2}) \sinh} \frac{4i(g_{1} + g_{2} \cosh)}{(4 + g_{2}^{2} g_{2}^{2}) \sinh}; (2.26)$$

$$T_{|(;g_{1};g_{2}) = T_{|(;g_{1};g_{2}) = \frac{(4 + g_{2}^{2} g_{2}^{2}) \sinh}{(4 + g_{1}^{2} g_{2}^{2}) \sinh} \frac{4i(g_{1} + g_{2} \cosh)}{(4 + g_{1}^{2} g_{2}^{2}) \sinh} \cdot (2.27)$$

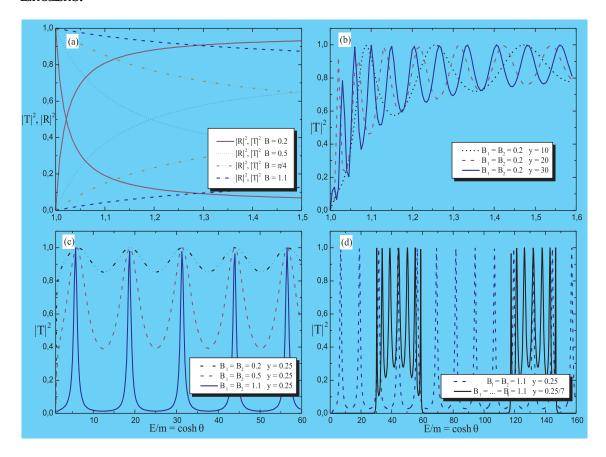


Figure 1: (a) Single defect with varying coupling constant. If \hat{f} and $\Re \hat{f}$ correspond to curves starting at 0 and 1 of the same line type, respectively. (b) Double defect with varying distance y. (c) Double defect with varying elective coupling constant B = arcsin($4g_1 = (4 + g_1^2)$). (d) Double defect dotted line, eight defects solid line.

Part (a) of gure 1 con mm s the unitarity relation (2.1). Part (b) and (c) show the typical resonances of a double defect, which become stretched out and pronounced with respect to the energy when the distance becomes smaller and the coupling constant increases, respectively. Part (d) exhibits a general feature, that is when the number of defects is increased, for xed distance between the outerm ost defects, the resonances become more and more dense in that region such that one may speak of energy bands.

2.3.2 The defect D (;;
$$Q_+$$
; Q_+) = iq=2(Q_+

This type of defect rem inds on the rst non-trivial charge occurring in the free Ferm ion model. In this case we compute by the samemeans the related transmission and rejection amplitudes to

$$R_{j}(;y) = R_{j}(;y) = R_{j}(;y) = R_{j}(;y) = R_{j}(;y) = \frac{4ig \cosh e^{2iym \sinh}}{4ig + \tanh (4 + g^{2} \cosh^{2})}; (2.28)$$

$$T_{j}() = T_{j}() = T_{j}() = T_{j}() = \frac{(4 + g^{2} \cosh^{2}) \tanh}{4ig + \tanh (4 + g^{2} \cosh^{2})}; (2.29)$$

2.4 Im purities coupled to laser elds

satis es D = D.

Let us now consider a m ore complex situation in which a three dimensional laser eld hits the quantum wire polarized in such a way that it has a vector eld component along the wire. Since the work of Weyl [32], one knows that matter may be coupled to light by means of a local gauge transform ation, which rejects itself in the usual minimal coupling prescription, i.e. @ ! @ ieA, with A being the vector gauge potential. The free Fermions in the wire are then described by the Lagrangian density

$$L_A = (i @ m + e A) : (2.30)$$

When the laser eld is switched on, we can solve the equation of motion associated to (2.30)

$$(i @ m + e A) = 0$$
 (2.31)

by a Gordon-Volkov type solution [33]

$$Z_{x}$$
 Z_{t} Z_{t

U sing now a linearly polarized laser eld along the direction of the wire, the vector potential can typically be taken in the dipole approximation to be a superposition of monochromatic

light with frequency!, i.e.

A (t) = A₁(t) =
$$\frac{1}{x} \int_{0}^{z} ds A_{0}(s) = \frac{1}{2} \int_{0}^{z} ds E(s) = \frac{E_{0}}{2} \int_{0}^{z} ds f(s) \cos(!s)$$
 (2.33)

with f (t) being an arbitrary enveloping function equal to zero for t < 0 and t >, such that denotes the pulse length. In the following we will always take f (t) = (t) (t), with (x) being again the H eavyside unit step function. The second equality in (2.33), A $_0$ (x;t) = xA-(t), follows from the fact that we have to solve (2.32).

I want to comment on the validity of the dipole approximation in this context. It consists usually in neglecting the spatial dependence of the laser eld, which is justified when x! < c = 1, where x is a representative scale of the problem considered. In the context of atom ic physics this is typically the Bohr radius. In the problem investigated here, this approximation has to hold over the full spatial range in which the Fermion follows the electric eld. We can estimate this classically, in which case the maximal amplitude is E = 0.

$$\frac{\text{eE}_{0}}{I}^{2} = 4U_{p} < 1;$$
 (2.34)

for the dipole approxim ation to be valid. Due to the fact that x is a function of!, we have now a lower bound on the frequency rather than an upper one as is more common in the context of atom ic physics. We have also introduced here the ponderom otive energy U_p for monochrom atic light, that is the average kinetic energy transferred from the laser eld to the electron in the wire.

The solutions to the equations of motion of the free system and the one which includes the laser eld are then related by a factor similar to the gauge transformation from the length to the velocity gauge

$$_{j}^{A}(x;t) = \exp [ixeA(t)]_{j}^{f}(x):$$
 (2.35)

In an analogous fashion one m ay use the same m in im al coupling procedure also to couple in addition the laser eld to the defect. One has to invoke the equation of motion in order to carry this out. For convenience we assume now that the defect is linear in the elds and . The Lagrangian density for a complex free Ferm ion with 'defects D (; ;A) of type at the position x_n subjected to a laser eld then reads

$$L_{AD} = L_A + \sum_{n=1}^{X'} D^{-n} (;;A) (x x_n):$$
 (2.36)

Considering for simplicity rst the case of a single defect situated at x=0, the solution to the equation of motion resulting from (2.36) is taken to be of the form ${A \atop j}(x;t)=(x){A \atop j;+}(x;t)+(x){A \atop j;}(x;t)$, which means as before we distinguish here by notation the solutions (2.35) on the left and right of the defect, ${A \atop j;}(x;t)$ and ${A \atop j;+}(x;t)$, respectively. Proceeding as before, the matching condition reads now

$$i^{1}(_{j;+}^{A}(x;t)) \qquad _{j;}^{A}(x;t))_{k=0} = \frac{(0D_{AD}(_{j;+}^{A})}{(0,_{j}^{A}(x;t))} = 0 : (2.37)$$

It is clear, that in this case the transm ission and re ection amplitudes will in addition to and galso depend on the characteristic parameters of the laser eld

$$T(;g;E_0;!;t)$$
 and $R(;g;E_0;!;t)$: (2.38)

With regard to the main theme of this talk, it is clear that the laser eld can be used to control the conductance. For instance defects which have transmission amplitudes of the form as the solid line in gure 1 (c), can be used as optically controllable switching devices. I want to deviate now slightly from the main line of argument and report brie y on an interesting phenomenon one can predict with solutions of the type (2.38).

2.5 Harm onic generation

Let me rst brie y explain what harm onics are. The rst experimental evidence can be traced back to the early sixties [34]. Franken et al found that when hitting a crystalline quartz with a weak ultraviolet laser beam of frequency!, it em its a frequency which is 2!. Generalizing this phenomenon to higher multiples, one says now adays that high harm onics generation is the non-linear response of a medium (a crystal, an atom, a gas, ...) to a laser eld. Harm onic generation is important, since it allows to convert infrared input radiation of frequency! into light in the extreme ultraviolet regime whose frequencies are multiples of! (even up to order 1000, see e.g. [35] for a recent review). A typical experimental spectrum is presented in gure 2.

In gases, composed of atoms or small molecules, this phenomenon is well-understood and, to som e extent, even controllable in the sense that the frequency of the highest harm onic, the so-called \cut-o ", visible in gure 2, can be tuned as well as the intensities of particular groups of harmonics. In more complex systems, however, for instance solids, or larger m olecules, high-harm onic generation is still an open problem. This is due to the fact that, until a few years ago, such system swere expected not to survive the strong laser elds one needs to produce such e ects. How-

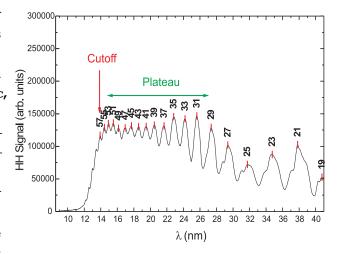


Figure 2: Harmonic spectrum for Neon for a TiSa laser with = 795nm. Measured at the Max Born Institut Berlin [36]

ever, now adays, with the advent of ultrashort pulses, there exist solid-state m aterials whose dam age threshold is beyond the required intensities of 10^{14} W =cm² [37]. As a direct consequence, there is an increasing interest in such materials as potential sources for high-harm onics. In fact, several groups are currently investigating this phenomenon in systems such as thin crystals [38, 39], carbon nanotubes [40], or organic molecules [41, 42].

We will therefore try to answer here the question, whether it is possible to generate harm on ics from solid state devices and as a prototype of such a system we study a quantum wire coupled to the laser eld in the way described in section 2.4.

In order to answer that question, we sty have to study the spectrum of frequencies which is litered out by the defect while the laser pulse is non-zero. The Fourier transform s of the re ection and transm ission probabilities provide exactly this inform ation

$$T(;;E_0;!;) = \frac{1}{2} \operatorname{dt} T(;E_0;!;t) \int_{0}^{2} \cos(t); \qquad (2.39)$$

$$R(;;E_0;!;) = \frac{1}{2} \operatorname{dt} R(;E_0;!;t) \int_{0}^{2} \cos(t); \qquad (2.40)$$

$$R(;;E_0;!;) = \frac{1}{2} \int_0^{2\pi} dt R(;E_0;!;t) \int_0^2 \cos(t):$$
 (2.40)

When parity is preserved for the rejection and transmission amplitudes, that is for real defects with D = D, we have $\mathcal{T} \hat{\mathcal{T}} + \mathcal{R} \hat{\mathcal{T}} = 1$, and it su ces to consider T in the following.

2.5.1 Type I defects

M any features can be understood analytically. Taking the laser eld in form of monochrom atic light in the dipole approximation (2.33), we may naturally assume that the transm ission probability for som e particular defects can be expanded as

$$\mathcal{J}_{I}(;U_{p};!;t)\hat{J} = \sum_{k=0}^{X^{1}} t_{2k}()(4U_{p})^{k} \sin^{2k}(!t); \qquad (2.41)$$

We shall refer to defects which adm it such an expansion as \type I defects". A ssum ing that the coe cients t_{2k} () become at most 1, we have to restrict our attention to the regime $4U_p < 1$ in order for this expansion to be meaningful for all t. Note that this is no further lim itation, since it is precisely the same constraint as already encountered for the validity of the dipole approximation (2.34). The functional dependence of (2.41) will turn out to hold for various explicit defects considered below. Based on this equation, we compute for such type of defect

$$T_{I}(;;U_{p};!;) = \sum_{k=0}^{X^{1}} \frac{(2k)!(U_{p})^{k} \sin()t_{2k}()}{Q_{k}!} : (2.42)$$

It is clear from this expression that type I defects will preferably let even multiples of the basic frequency! pass, whose amplitudes will depend on the coe cients t_{2k} (). When we choose the pulse length to be integer cycles, i.e. = 2 n=! for n 2 Z, the expression in (2.42) reduces even further. The values at even multiples of the basic frequency are simply

$$T_{I}(2n!;;U_{p}) = (1)^{n} t_{2k}()(U_{p})^{k} 2k$$

$$k n$$
(2.43)

which becomes independent of the pulse length. Notice also that the dependence on E_0 and ! occurs in the combination of the ponderom otive energy U_p . Further statem ents require the precise form of the coe cients t $_{2k}$ () and can only be made with regard to a m ore concrete form of the defect.

2.5.2 Type II defects

C learly, not all defects are of the form (2.41) and we have to consider also expansions of the type

$$\mathcal{I}_{\text{II}}(;\mathbf{E}_0 = \mathbf{e};!;t) \hat{\mathcal{I}} = \sum_{\substack{k,p=0}}^{x^{\underline{1}}} t_{2k}^{p}() \frac{\mathbf{E}_0^{2k+p}}{!^{2k}} \cos^p(!t) \sin^{2k}(!t); \qquad (2.44)$$

We shall refer to defects which adm it such an expansion as $type\ II\ defects$. In this case we obtain

We observe from this expression that type Π defects will liter out all multiples of!. For the pulse being once again of integer cycle length, this reduces to

$$T_{\text{II}}(2n!;;U_p;E_0) = \begin{cases} x^{k} & x^{p} \\ x^{p=0} & = 0 \end{cases} (1)^{k+n} \frac{t_{2k}^{2p}()}{2^{21} 2^{p}} (U_p)^{k+p} E_0^{2p} & p & 2k+21 \\ 1 & k+1 & n \end{cases} (2.46)$$

and

$$T_{II}((2n 1)!;;E_0=e) = \begin{cases} x^{\frac{1}{2}} & x^{p} \\ & (1)^{\frac{1}{2}+n+1} \frac{t^{2p+1}_{2k}()}{2^{21} \cdot 2p+1} (U_p)^{k+p} \\ & ! \\ & p \\ & \frac{(2k+2l)!(2n 1)E_0^{2p+1}}{(1+k n+1)!(1+n+k)!} \end{cases} (2.47)$$

which are again independent of . We observe that in this case we can not combine the E $_{\rm 0}$ and ! into a U $_{\rm p}$.

2.5.3 One particle approxim ation

In spite of the fact that we are dealing with a quantum eld theory, it is known that a one particle approximation to the Dirac equation is very useful and physically sensible when the external forces vary only slowly on a scale of a few Compton wavelengths, see e.g. [43]. We may therefore do not the spinor wavefunctions

$$_{j,v}$$
; $(x;t)^{y} := {}^{A}_{j} (x;t)^{y} \frac{a_{j}^{y}()}{q} = {}^{e}_{j} \frac{ip_{j} \times v_{j}}{2 p_{j}^{0}} v_{j}()^{y} :$ (2.49)

With the help of these functions we obtain then for the defect system

and the same function with u! v. Since this expression resembles a free wave, it can not be normalized properly and we have to localize the wave in form of a wave packet by multiplying with an additional function, g(p;t) in (2.20) and its counterpart g(x;t) in (2.50), typically a G au ian. Then for the function $A_{i;u}$, $A_{i;$

2.5.4 Harm onic spectra

We are now in the position to determ ine the emission spectrum for which we need to compute the absolute value of the Fourier transform of the dipole moment

$$X_{j_{ju}}$$
; () = $\int_{0}^{Z} \int_{0}^{D} \int_{0}^{A} (x;t)^{y} x_{j_{ju}}^{A}$; (x;t) expit : (2.51)

We localize now the wave packet in a region much smaller than the classical estimate for the maximal amplitude the electron will acquire when following the laser eld. We achieve this with a Gau ian $g(x;t) = \exp(x^2 - t)$, where $eE_0 = t^2$.

2.5.5 An exam ple: Im purity of energy operator type

As mentioned this type of defect, i.e. D (;) = g (x) can be obtained in a lim it from the defect discussed in section 2.3.1. Coupling the vector potential minimally to it yields

$$D_{AD}(;;A) = g(1 + e - M);$$
 (2.52)

by invoking the equation of motion. We can now determ in the rejection and transmission amplitudes as outlined above

$$R_{i}(;g;A=e;y) = R_{i}(;g;A=e;y) = R_{i}(;g;A=e;y) = R_{i}(;g;A=e;y) = \frac{[yA - \cosh]e^{2iy \sinh }}{[1 yA - \cosh] \frac{q}{4}[\frac{4}{r^{2}} + 1 + A^{2} y^{2}A^{2}] \sinh} : \qquad (2.53)$$

We denoted the dierentiation with respect to time by a dot. The transmission amplitudes turn out to be

$$T_{i}(;g;A=e;y) = T_{i}(;g;A=e;y) = T_{i}(;g;A=e;y) = T_{i}(;g;A=e;y) = T_{i}(;g;A=e;y) = \frac{i \cdot 1 \quad y^{2}A^{2} + (A \quad \frac{2i}{g})^{2} \sinh}{\frac{4}{g}[1 \quad yA-\cosh] \quad i\frac{4}{g^{2}} + 1 + A^{2} \quad y^{2}A^{2}]\sinh} :$$
 (2.54)

Locating the defect at y = 0, the derivative of A does not appear anymore explicitly in (2.53) and (2.54), such that it is clear that this defect is of type I and adm its an expansion of

the form (2.41). W ith the explicit expressions (2.53) and (2.54) at hand, we can determ ine all the coe cients $t_{2k}()$ in (2.41) analytically. For this purpose let us set bring the transm ission amplitude into the more symmetric form

with

$$a_0(;g) = 16g^2 + (4 + g^2)^2 \sinh^2;$$
 $a_0(;g) = (g^2 + 4)^2 \sinh^2;$ (2.56)

$$a_2(;g) = 2g^2(4+g^2)\sinh^2;$$
 $a_4(;g) = g^4\sinh^2:$ (2.57)

We can now expand $f(g;A)^2$ in powers of the eld A (t) and identify the coe cients $t_{2k}(g)$ in (2.41) thereafter. To achieve this we simply have to carry out the series expansion of the denominator in (2.55). The latter admits the following compact form

$$\frac{1}{a_0(;g) + a_2(;g)A^2 + a_4(;g)A^4} = \sum_{k=0}^{x^k} c_{2k}(;g)A^{2k}; \qquad (2.58)$$

 $w \pm c_0 (;g) = 1=a_0 (;g)$ and

$$c_{2k}(;g) = \frac{c_{2k-2}(;g)a_2(;g) + c_{2k-4}(;g)a_4(;g)}{a_0(;g)};$$
(2.59)

for k>0. We understand here that all coe cients c_{2k} with k<0 are vanishing, such that from this formula all the coe cients c_{2k} may be computed recursively. Hence, by comparing with the series expansion (2.41), we note that following closed formula for the coe cients c_{2k} (;g)

$$t_{2k}(;q) = [a_0(;q) \ a_0(;q)]c_{2k}(;q) \ k > 0:$$
 (2.60)

The rst coe cients then simply read

$$t_0(;g) = \frac{a_0(;g)}{a_0(;g)} = \text{I}(;E_0 = 0)\text{I}; \qquad (2.61)$$

$$t_2(;g) = \frac{a_2(;g)}{a_0(;g)} [1 \quad t_0(;g)] = \frac{8g^4(4+g^2)\sinh^2 2}{(16g^2+(4+g^2)^2\sinh^2)^2}; \quad (2.62)$$

$$t_4(;g) = \frac{a_4(;g)}{a_2(;g)} \frac{a_2(;g)}{a_0(;g)} t_2(;g); \qquad (2.63)$$

and so on. It is now clear how to obtain also the higher term s analytically, but since they are rather cum bersom e we do not report them here.

Having computed the coe cients t_{2k} , we can evaluate the series (2.42) and (2.43) in principle to any desired order. For some concrete values of the laser and defect parameters the results of our evaluations are depicted in gure 3.

The main observation from part (a) is that the defect acts as a liter selecting higher harm onics of even order of the laser frequency. Furtherm ore, from the zoom of the peak

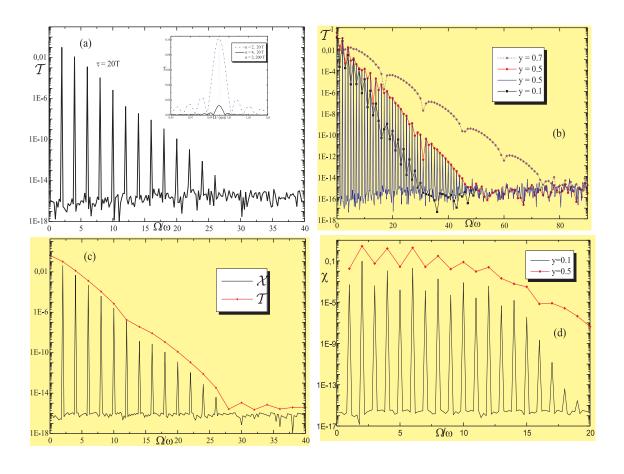


Figure 3: Fourier transform of the transm ission probability for a single (a) and double (b) defect with $E_0 = 2.0$, g = 3.5, = 1.2, ! = 0.2. Harm onic em ission spectrum for a single (c) and double (d) defect with $E_0 = 2.0$, g = 3.5, = 1.2, ! = 0.2, = 6.

regions, we see that there are satellite peaks appearing near the main harmonics. They reduce their intensity when is increased, such that with longer pulse length the harmonics become more and more pronounced. We also investigated that for dierent frequencies! the general structure will not change. Increasing the eld amplitude E_0 , simply lifts up the whole plot without altering very much its overall structure. We support these notings in two alternative ways, either by computing directly (2.39) numerically or, more instructively, by evaluating the sums (2.42) and (2.43).

Part (b) shows the analysis for a double defect system with one defect situated at x = 0 and the other at x = y. The double defect amplitudes are computed directly from (2.12) and (2.13) with the expression for the single defect (2.53) and (2.54). Since now both A and A-appear explicitly in the formulae for the R's and T's, it is clear that the expansion of the double defect can not be of type I, but it turns out to be of type II, i.e. of the form (2.44). Hence, we will now expect that besides the even also the odd multiples of! will be litered out, which is indeed visible in part (b) for various distances. Here we have only plotted a continuous spectrum for y = 0.5, whereas for reasons of clarity, we only drew the enveloping function which connects the maxima of the harmonics for

the remaining distances. We observe that now not only odd multiples of the frequency emerge in addition to the ones in (a) as harmonics, but also that we obtain much higher harmonics and the cut-o is shifted further to the ultraviolet. Furthermore, we observe a regular pattern in the enveloping function, which appears to be independent of y. Sim ilar patterns were observed before in the literature, as for instance in the context of atom ic physics described by a K lein-G ordon form alism (see gure 2 in [44]).

Coming now to the main point of our analysis we would like to see how this structure is rejected in the harmonic spectra. The result of the evaluation of (2.51) is depicted in gure 3 parts (c) and (d). We observe a very similar spectrum as we have already computed for the Fourier transform of the transmission amplitude, which is not entirely surprising with regard to the expression (2.51). The cut-offrequencies are essentially identical. From the comparison between X and the enveloping function for T we deduce, that the term involving the transmission amplitude clearly dominates the spectrum.

The important general deduction from these computations is of course that harmonics of higher order do emerge in the emission spectrum of impurity systems, such that harmonics can be generated from solid state devices.

3. Conductance from the Kubo formula

Having characterized various features of defects, I will proceed with the main them e of the talk, that is the computation of the DC conductance. In the absence of impurities it can be obtained from the Kubo formula in the form

G (T) =
$$\lim_{! \ 0} \frac{1}{2!} \sum_{1}^{Z_{1}} dt e^{i!t} hJ(t) J(0) i_{T,m}$$
: (3.1)

We proposed in [1] a generalization of (3.1) in the form of (1.1). The key quantity needed for the explicit computation of (3.1) or (1.1) are the occurrence of the temperature dependent current-current correlation functions hJ (r) J (0) $i_{T,m}$ or hJ (r) Z J (0) $i_{T,m}$, respectively.

In the zero temperature regime two-point correlation functions can be computed in general by means of the form factor bootstrap approach [15, 16, 17]. In this approach one expands the two-point function between two local operators 0 and 0 $^{\circ}$ in terms of the series

$$O(r)O^{0}(0) = \sum_{m=0,m}^{X} = \begin{cases} X^{m} & X \\ X^{m} & \frac{d_{1}}{m!(2)^{n}} \end{cases} \xrightarrow{Y^{n}_{0}} e^{rm_{i} cosh_{i}} e^{rm_{i} cosh_{i}}$$

$$F^{Oj_{1} ::::_{n}} (1; :::;_{n}) F^{Oj_{1} ::::_{n}} (1; :::;_{n}) ; (3.2)$$

where we choose x = (ir; 0). The form factors are de ned as matrix elements of the local operator 0 (x) located at the origin between a multiparticle in-state and the vacuum,

$$F_n^{0j_1:::_n}(1;2:::;_n) = h_0 p(0) p_1^y(1) Z_1^y(1) Z_2^y(2) ::: Z_n^y(n) i:$$
 (3.3)

The expansion (3.2) is simply obtained by inserting complete states on the rhs. One may proceed similarly by inserting one more set of complete states when a defect is present and

obtains

$$hJ(r)Z J(0)i_{T=0,m} = \sum_{\substack{n,m=1 \ 1 \ n; 1 \ m}} \frac{d_1 ndd_1 m d_1 m}{m \ln!(2)^{n+m}} F_n^{d_{j_1} :::: n} (1 :::: n)$$

$$E \qquad E \qquad F_m^{p_m ::: x_1} (1) \not Z \not Z_1 (1) ::: Z_m (m) F_m^{j_1 ::: m} (1 :::: m) e^{i=1} :: (3.4)$$

This means there are three principle steps left in order to obtain the conductance from the expression in (1.1). (a) The computation of the form factors (3.3) and the matrix elements involving the defect operator occurring in (3.4). (b) The integration in r and (c) the limit!! 0. Step (a) can be performed in two alternative ways either by solving certain consistency equations for the form factors and defect matrix elements or by direct computation. For the latter we require a representation for the particle creation operators Z (), the defect operator Z and the local operator O (r) which is the current in this case.

3.1 The massless lim it

Remarkably when carrying out the massless limit of the above expressions, the steps (b) and (c) can be carried out generically. To perform such a limit we proceed according to the massless limit prescription as suggested originally in [45]. It consists of carrying out the limit m ! 0 in the high energy regime. In order to do this one replaces in every rapidity dependent expression by , where an additional auxiliary parameter has been introduced. Thereafter one takes the limit ! 1, m ! 0 while keeping the quantity $m^2 = m = 2 \exp(1)$ nite. For instance, carrying out this prescription for the momentum yields $p = m^2 \exp(1)$, such that one may view the model as splitted into its two chiral sectors and one can speak naturally of left (L) and right (R) movers. For the form factors in (3.4) the massless limit yields

$$\lim_{\substack{1 \\ 1}} F_n^{0j_1 ::: n} (_1 + _1 ;:::; _n + _n) = F_{1 n}^{0j_1 ::: n} (_1 ;:::; _n); \tag{3.5}$$

with $_{i}$ = 1 and $_{i}$ = R for $_{i}$ = + and $_{i}$ = L for $_{i}$ = . Namely, in the massless limit every massive n-particle form factor is mapped into 2^{n} massless form factors. Using these expressions, performing a W ick rotation and introducing the variable E = $_{i=1}^{n}$ m $_{i}$ e $_{i}$, we obtain from (3.4)

We note that for the massless prescription to work, the matrix element involving the defect Z can only depend on the rapidity dierences, which will indeed be the case as we see below. Performing the variable transformation $_n$! $\ln E \stackrel{0}{=} \hat{m}_n$ $_{i=1}^p \hat{m}_i = \hat{m}_n e^i$, we rewrite the rhs. of (3.6) as

We substitute now this correlation function into the Kubo formula, shift all rapidities as $i ! i + ln E \stackrel{0}{\to} n_n$, $i ! i + ln E \stackrel{0}{\to} n_n$, use the Lorentz invariance of the form factors and carry out the integration in dE 0

$$G = \lim_{\substack{! \ ! \ 0}} \frac{!^{2s}}{m^{2s}_{n}} \times \frac{X}{m^{2s}_{n}} \times \frac{Z^{0}}{n!(2)^{n}} \frac{d_{1} \quad n \cdot p}{m!(2)^{n}} \frac{d^{2s}}{m!(2)^{m}} \frac{d_{1} \quad m}{1} \frac{1}{p^{n}_{1} \cdot m^{n}_{1} \cdot m} \frac{1}{m!(2)^{m}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1}} \times \frac{1}{p^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1}} \times \frac{1}{p^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1}} \times \frac{1}{p^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1} \cdot m^{n}_{1}} \times \frac{1}{p^{n}_{1} \cdot m^{n}_{1}} \times$$

We state various observations: Since the matrix element involving the defect only depends on the rapidity dierence, it is not a ected by the shifts. Operators with Lorentz spin s=1 play a very special role in (3.8), which makes the current operator especially distinguished. In that case the rhs. of (3.8) becomes independent of the frequency! and the limit is carried out trivially. Furthermore, since the nalexpression has to be independent of m_n , we deduce that the form factors have to be linearly dependent on m_n .

3.2 Realization of the defect operator

A realization of Z can be achieved very much in analogy to a realization of local operators, i.e. as exponentials of bilinears in Zam olodchikov {Faddeev operators [46]. For the case of a boundary a generic model independent realization for the boundary operator B was originally proposed in [28] for the parity invariant case, i.e. R = R. This proposal was generalized to the defect operator in [26] with the same restriction and for self-conjugated particles. Here we extend this realization in order to incorporate the possibility of parity breaking as well as non self-conjugated particles. A non-trivial consistency check for the validity of our proposal will be ultimately provided when exploiting it in the computation of the conductance, obtained by entirely dierent means as will be presented in part II. The realization we want to propose here is a direct generalization of the one presented in [26], namely

$$Z = :\exp\left[\frac{1}{4} \int_{1}^{Z_{1}} D()d]:;$$
 (3.9)

where: : denotes normal ordering and the operator D () has the form

$$F_n^{\circ j_1 ::: n} (_1 + _j :::; _n +) = e^s F_n^{\circ j_1 ::: n} (_1 ;:::; _n):$$

²Denoting by s the Lorentz spin of the operator O and being a constant, the form factors satisfy

with K_i () = R_i ($\frac{i}{2}$), K_i () = R_i ($\frac{i}{2}$), W_i () = T_i ($\frac{i}{2}$) and W_i () = T_i ($\frac{i}{2}$). In comparison with [26] we have used a slightly different normalization factor, since in general we have contributions in the sum over i in (3.10) including both particles and anti-particles, as for the complex free Ferm ion we shall treat below. Following the arguments given in [28], the operator D () depends on the amplitudes R(), T(), R() and T() with their arguments shifted, as considered also in [24, 26].

3.3 D efect m atrix elem ents

Having now a concrete generic realization of the defect (3.9), we can compute the defect matrix elements. One way of doing this is to solve a set of consistency equations which relate the lower particle matrix elements to higher particle ones, similar as in the standard form factor program [15, 16, 17]. Such kind of iterative equations were proposed in [24] for a parity invariant defect and for a real free fermionic and bosonic theory. We generalize this here and note institute operator (3.9) becomes

$$\lim_{\substack{R,R'! \ 0;T;T'! \ 1}} Z = : \exp\left[\frac{1}{2} \int_{1}^{Z_{1}} X \left(\sum_{i=1}^{Y} (i)Z_{i}(i) \right) \right];;$$
 (3.11)

and the defect should act in this case as the identity operator, which xesour normalization to hZ $_{i}$ ($_{1}$)Z $_{j}$ ($_{2}$)i = 2 ($_{12}$) $_{ij}$ after having contracted according to W ick's theorem . For two particles we nd,

$$hZ_{\{(1)}Z_{i}(2)Z_{i} = \hat{K}_{i}(2)(\hat{1}_{2});$$
 (3.12)

$$hZ Z_{i}^{y}(_{1})Z_{i}^{y}(_{2})i = K_{i}^{x}(_{1}) (_{12}^{x});$$
 (3.13)

$$hZ_{i}(_{1})Z Z_{j}^{Y}(_{2})i = \hat{W}_{i}(_{1}) (_{12})_{ij}$$
: (3.14)

For later convenience we have introduced the functions

$$\hat{K}_{i}() = K_{i}() + S_{i}(2)K_{i}() + S_{i}(2)K_{i}() + S_{i}(2)K_{i}() + S_{i}(2)K_{i}()$$
 (3.15)

$$\hat{\mathbb{W}}_{i}\left(\;\right) = \,\mathbb{W}_{i}\left(\;\right) + \,\mathbb{W}_{i}\left(\;\right) \,=\, \hat{\mathbb{W}}_{i}\left(\;\right) \,+\, \mathbb{W}_{i}\left(\;\right) \,=\, \hat{\mathbb{W}}_{i}\left(\;\right) \,; \tag{3.16}$$

since the K $_{i}$, K $_{i}$, W $_{i}$ and W $_{i}$ amplitudes de ned before will repeatedly appear in the combinations (3.15), (3.16) in what follows. The latter equalities in (3.15), (3.16) follow $\sin p \ln p$ from

$$\mathbb{W}_{\text{i}} \text{ ()} = \mathbb{W}_{\text{ }} \text{ ()} = \mathbb{W}_{\text{ }} \text{ (i))} \text{ ; } \mathbb{K}_{\text{i}} \text{ ()} = \mathbb{S}_{\text{i}} \text{ (2)} \mathbb{K}_{\text{ }} \text{ ()} = \mathbb{S}_{\text{i}} \text{ (2)} \mathbb{K}_{\text{ }} \text{ (i))} \text{ ; (3.17)}$$

which are in turn consequences of the crossing-herm iticity properties (2.3)-(2.4). With these matrix elements we can construct the ones involving more particles recursively from

$$F^{m ::: 1 ::: 1 ::: 1} (_{m} ::: _{1}; _{1}^{0} ::: _{n}^{0}) = Z_{m} (_{m}) ::: Z_{1} (_{1}) Z_{2} Z_{1}^{y} (_{1}^{0}) ::: Z_{n}^{y} (_{n}^{0}) = X^{m} (_{11}) \hat{K}_{1} (_{1}) S_{1p} (_{1p}) F^{m ::: _{1} ::: _{2} 1 ::: _{n}^{1}} (_{m} ::: _{1} ::: _{2}; _{1}^{0} ::: _{n}^{0}) (3.18)$$

$$\downarrow = 2 \qquad \qquad p = 1$$

$$X^{m} (_{11}) \hat{K}_{1} (_{1}) S_{1p} (_{1p}) F^{m ::: _{2} 1 ::: _{1} :$$

Here we denoted with the check on the rapidities—the absence of the corresponding particle in the matrix element. It is clear from the expressions (3.9) and (3.10) that the only possible non-vanishing matrix elements (3.18) are those when n + m is even. Taking (3.12)-(3.14) as the initial conditions for the recursive equations (3.18)-(3.19), we can now either solve them iteratively or use (3.9) and evaluate the matrix elements directly. Closed solutions for these equations have been presented for the rst time in [1].

3.4 Free Ferm ion wire with impurities

At this point we have to abandon the general discussion and consider a concrete theory, which for the reasons already explained we choose to be the complex free Ferm ion. Then the generators of the ZF-algebra Z $_{i}$ (); Z $_{i}^{y}$ () are just the usual creation and annihilation operators a_{i} (); a_{i}^{y} ().

3.4.1 D efect m atrix elem ents

Let us now use (3.9)-(3.10) in order to evaluate m atrix elements involving the defect operator. In what follows, the most relevant matrix elements are those involving four particles, for which we compute

with the abbreviations

$$w_{i}(x_{i}, x_{i}) = x_{i}^{2}\hat{w}_{i}(x_{i})\hat{w}_{i}(x_{i})$$
 and $k_{i}(x_{i}, x_{i}) = x_{i}^{2}\hat{k}_{i}(x_{i})\hat{k}_{i}(x_{i})$: (3.20)

One can now try to $\ \,$ nd solutions for all n-particle form factors either from (3.18)-(3.19) or by direct computation. For instance for the stated choice of particles involved, we compute

$$F^{m} \stackrel{\text{(i() } n}{\text{(ii)}} (\ _{2m} \ ::: \ _{1}; \ _{1}^{0} \ ::: \ _{2n}^{0}) = \sum_{k=0}^{m \ \text{in}} (n,m) \frac{(1)^{m+n} \ _{2k} \ _{n+m}}{(m \ k)!(n \ k)!k!k!} \frac{Z}{1} d_{1} ::: d_{2n+2m} det A^{2n} (\ _{1} ::: \ _{2n}; \ _{1}^{0} ::: \ _{2n}^{0}) det A^{2m} (\ _{2n+1} ::: \ _{2n+2m}; \ _{1} ::: \ _{2m})$$

$$Y^{k} \qquad \qquad W_{i} (\ _{2p}) W_{i} (\ _{2p} \ _{1}) (\ _{2p} \ _{2n+2p}) (\ _{2p} \ _{1} \ _{2n+2p} \ _{1})$$

$$p=1 + k \qquad p=1+k+n \qquad p=1+k+n \qquad (3.21)$$

where A'(1::: \cdot ; 01::: \cdot) is a rank 'm atrix whose entries are given by

$$A_{ij} = \cos^2[(i \ j) = 2] (_i \ _j^0); \qquad 1 \ i; j \ ':$$
 (3.22)

The matrix elements are computed similarly as in [6] and references therein. Likewise we compute

$$F^{n i+m i}(_{n} ::: _{1}; _{1}^{0} ::: _{m}^{0}) = _{n,m} \frac{^{n}(_{1})^{n} ^{1}}{^{n}!} X_{1}^{1} d_{1} ::: d_{n} W_{i}(_{k})$$

$$\det B^{n}(_{n} ::: _{1}; _{1} ::: _{n}) \det B^{n}(_{1} ::: _{n}; _{1}^{0} ::: _{n}^{0}); \qquad (3.23)$$

where we introduced a new rank 'm atrix B' ($_1::::_{i}$) whose entries are now simply given by

$$B_{ij} = (i_{i} \quad 0_{j}); \qquad 1 \quad i; j \quad 1$$

One can verify explicitly [1] that these expressions indeed satisfy (3.18) and (3.19).

3.4.2 Conductance in the T = m = 0 regime

It is well-known that for a free Ferm ion theory (also for a single complex free Ferm ion) the conform all (1)-current-current correlation function is simply

hJ (r)J (0)
$$i_{T=m=0} = \frac{1}{r^2}$$
: (3.25)

This expression can also be obtained by using the expansion (3.2), together with the massless prescription as outlined above and the expressions for the only non-vanishing form factors of the current operator in the complex free Fermion theory

$$F_2^{Jj(i)}(; \gamma) = F_2^{Jj(i)}(; \gamma) = i m e^{\frac{+^2}{2}}$$
: (3.26)

In particular, the m assless lim it of the previous expressions gives, according to the m assless prescription,

$$F_{RR}^{Jj|i}(;\gamma) = F_{RR}^{Jj|i|}(;\gamma) = 2 \text{ inf } e^{\frac{+\gamma}{2}};$$
 (3.27)

$$F_{LL}^{J\dot{J}\dot{L}}(;\gamma) = F_{LR}^{J\dot{J}\dot{L}}(;\gamma) = F_{RL}^{J\dot{J}\dot{L}}(;\gamma) = F_{LL}^{J\dot{J}\dot{L}}(;\gamma) = F_{LR}^{J\dot{J}\dot{L}}(;\gamma) = F_{RL}^{J\dot{J}\dot{L}}(;\gamma) = 0:(3.28)$$

We these expressions we can evaluate (32) to (325). We may the insert (325) into (3.1) and the problem is reduced to and the Fourier transform of the function r^2 , which is given by $P_1^{R_1}$ dre^{i! r} $r^2 = 1$! for ! > 0, with P denoting the principle value. This yields in the absence of a defect G (0) = 1=2, in complete agreement with the well-known classical expression for the conductance in a wire without any impurities, see for instance [47].

For the m ore com plicated situation of n defects Z $_1$ $_n$ located in space at positions Y $_1$:: y $_n$, we com pute in the zero tem perature and zero m ass regime

hJ (r)Z₁
$$_{n}$$
 JZ(0) $i_{T=m=0} = \frac{m^{2}}{2} {\overset{Z}{X}} {\overset{Z}{4}} {\overset{d}{=}} \frac{d_{1}}{2} e^{-2mn^{2} \cosh_{1} x} \hat{K}_{i}^{x} (_{1}) {\overset{Z}{=}} \frac{d_{2}}{2} \hat{K}_{i}^{x} (_{2})$

$$+ {\overset{Z}{=}} \frac{d_{1}}{2} e^{-1} {\overset{mn^{2}}{=}} {\overset{Z}{W}}_{i}^{x} (_{1}) {\overset{d}{=}} \frac{d_{2}}{2} e^{-2} {\overset{mn^{2}}{=}} {\overset{Z}{W}}_{i}^{x} (_{2})^{5} : (3.29)$$

The functions $\hat{W}_i^{\hat{R}}$ (), $\hat{K}_i^{\hat{R}}$ (), ::: de ned in (3.29) are the massless limits of the corresponding functions \hat{W}_i (), \hat{K}_i (), ::: For all the defects we considered, it turned out that the rst contribution to the previous correlation function is actually vanishing, so that (3.29) is considerably simplied. In many of the examples, this is due to the fact that the amplitudes \hat{K}_i () are vanishing in the rst place, as a consequence of the crossing relations (3.17). The vanishing of the relection part in (3.29) also occurs in some cases as a consequence of the parity of the function \hat{K}_i (). For instance, we not that, for the energy operator defect such function, although initially non-vanishing, satis es \hat{K}_i () = \hat{K}_i (), such that $\lim_{m \to \infty} \hat{K}_i$ d \hat{K}_i () = 0.

We can now either use (3.29) to compute the conductance or evaluate the expression (3.8) directly in which the frequency lim it is already taken, in both cases we obtain

G (0) =
$$\frac{1}{2(2)^3}$$
 $X = Z^0$ d e w_{if} [ln(1 e);]: (3.30)

There are, in addition, further generic results which can be obtained independently of the speci c form of the defect. We present them at this stage and will con rm their validity below by some speci c examples. Specializing to the case in which all 'defects are of the same type and equidistantly separated, i.e. $y = y_1 = \frac{\pi}{n}$. We can identify two distinct regimes

$$w_{i\{}^{\Re R}(_{1;2}) = \begin{pmatrix} \frac{(_{\hat{W}_{i}}^{\Re R}(_{1})\hat{W}_{i}^{\Re R}(_{2})}{(_{1})\hat{W}_{i}^{\Re R}(_{2})} & \text{for nite y} \\ \hat{W}_{i}^{\Re R}(_{1})\hat{W}_{i}^{\Re R}(_{2}) & \text{for y ! 0} \end{pmatrix}$$
(3.31)

where we used in addition (3.16). Supported by our explicit examples below, we not that for y! 0 in (3.31) the amplitudes $\hat{W}_i^{\ \ \ }$ () become independent functions of the rapidity. As we have already arqued above

$$k_{ii}^{\Re R} (1; 2) = 0$$
: (3.32)

It will turn out, that the two regimes specied in (3.31) are also of a very distinct nature in the TBA context as presented in part II.

3.4.3 A wire with impurities of energy operator type

Let us exem plify the working of the above form ulae with a concrete defect operator. As a simple example we choose the energy operator defect as presented in section 2.3.1. Considering rst a wire possessing a single defect of this type, we compute

$$\hat{W}_{i}() = \frac{4 \cos B \cosh^{2}}{\cosh 2 + \cos 2B}; \quad \hat{K}_{i}() = \frac{2i \sin B \sinh}{\sin B \cosh}; \quad w_{i}^{\Re R}(_{1; 2}) = (2 \cos B)^{2}$$
(3.33)

with B being the e ective coupling constant as de ned in the caption of gure 1, such that

hJ (r)Z J (0)
$$i_{T=m=0} = \frac{\cos^2 B}{r^2} =$$
 G (0) = $\frac{\cos^2 B}{2}$: (3.34)

It will turn out that this is in complete agreement with the corresponding result from the Landauer formula (1.1).

Proceeding in the same way for a wire with two or four impurities we evaluated [1] in the regime y

hJ (r)Z ₁Z ₂J (0)i_{T=m=0} =
$$\frac{4 + \sin^4 B}{r^2 \cos^2 (2B) + 3^2}$$
; (3.35)

$$G^{-1-2}(0) = \frac{2 - 1 + \sin^4 B}{\beta - \cos^2 (2B)^2};$$
 (3.36)

hJ (r)Z
$$_{1}$$
Z $_{2}$ Z $_{3}$ Z $_{4}$ J (0) $i_{T=m=0} = \frac{1}{2r^{2}}$ 1 + $\frac{\cos^{8} B}{[\cos^{4} B \ 2(1 + \sin^{2} B)^{2}]^{2}}$; (3.37)
G $_{1}^{2}$ $_{3}$ $_{4}$ (0) = $\frac{1}{4}$ 1 + $\frac{\cos^{8} B}{[\cos^{4} B \ 2(1 + \sin^{2} B)^{2}]^{2}}$: (3.38)

$$G^{-1-2-3-4}(0) = \frac{1}{4} + \frac{\cos^8 B}{[\cos^4 B + 2(1+\sin^2 B)^2]^2} : (3.38)$$

In the regime y : 0, we obtained [1]

$$\lim_{y!} hJ(r)Z_{1}Z_{2}J(0)i_{T=m=0} = \frac{1}{r^{2}} \frac{\cos^{4}B}{(1+\sin^{2}B)^{2}};$$
(3.39)

$$\lim_{y = 0} G^{-1/2}(0) = \frac{1}{2} \frac{\cos^4 B}{(1 + \sin^2 B)^2};$$
 (3.40)

$$\lim_{y! = 0} hJ(r)Z_{1}Z_{2}Z_{3}Z_{4}J(0)i_{T=m=0} = \frac{1}{r^{2}} \frac{\cos^{4}B}{\cos^{4}B} \frac{2}{2(1+\sin^{2}B)^{2}}; \quad (3.41)$$

$$\lim_{y \stackrel{!}{=} 0} G^{-1-2-3-4}(0) = \frac{1}{2} \frac{\cos^4 B}{\cos^4 B} \frac{2}{2(1+\sin^2 B)^2} : (3.42)$$

It will turn out that we can reproduce these expressions by evaluating the Landauer form ula (12) when computing the densities with the help of the TBA. This will now be outlined in part II together with the general conclusions concerning also this part.

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